

PRELIMINARY
 Notice: This is not a final specification.
 Some parametric limits are subject to change.

MITSUBISHI <STD LINEAR ICs>

M6255X Series

GENERAL PURPOSE C•MOS OP AMP(SINGLE/DUAL/QUAD)

DESCRIPTION

The M6255X is a single power supply system semiconductor integrated circuit designed to be used for general-purpose arithmetic amplifier of general electronic equipment for consumer appliances.

This IC adopts C-MOS structure to achieve low power consumption and is therefore optimum for the recent boom in portable electronic equipment. The IC is also available for various applications for its full swing in both input and output, though the IC has a single power supply.

FEATURES

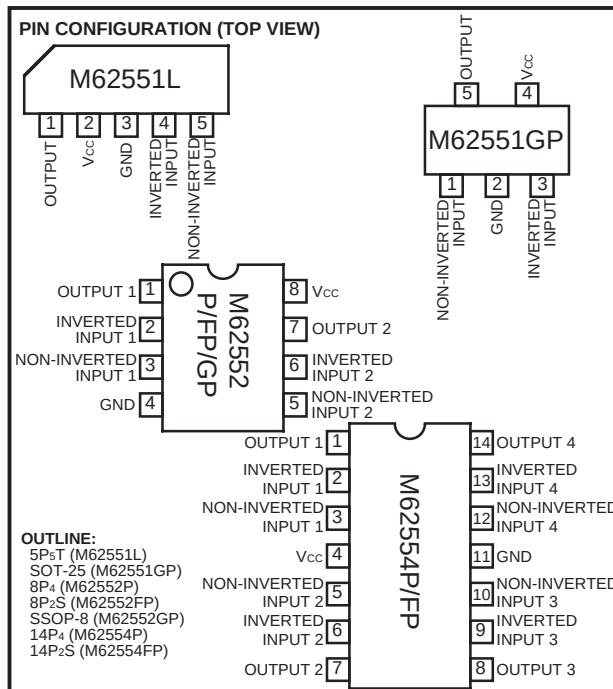
- Dissipation current.....0.19/0.38/0.76mA<551/552/554> (TYP)
- Output wide..... $V_o = \text{GND to } V_{cc}$ ($V_{in} = \text{GND to } V_{cc}$)
- Slew rate.....SR=1.2V/ μ S (TYP)
- Small size SSOP package. (551GP/ 552GP)

APPLICATION

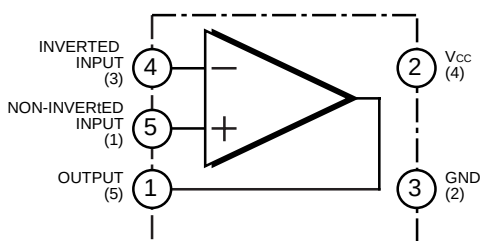
Various types of arithmetic circuits for ink jet printer and other general electronic equipment

RECOMMENDED OPERATING CONDITIONS

Supply voltage.....5V

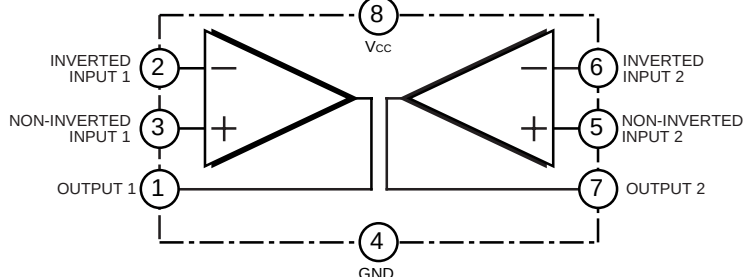


BLOCK DIAGRAM (M62551L/GP)

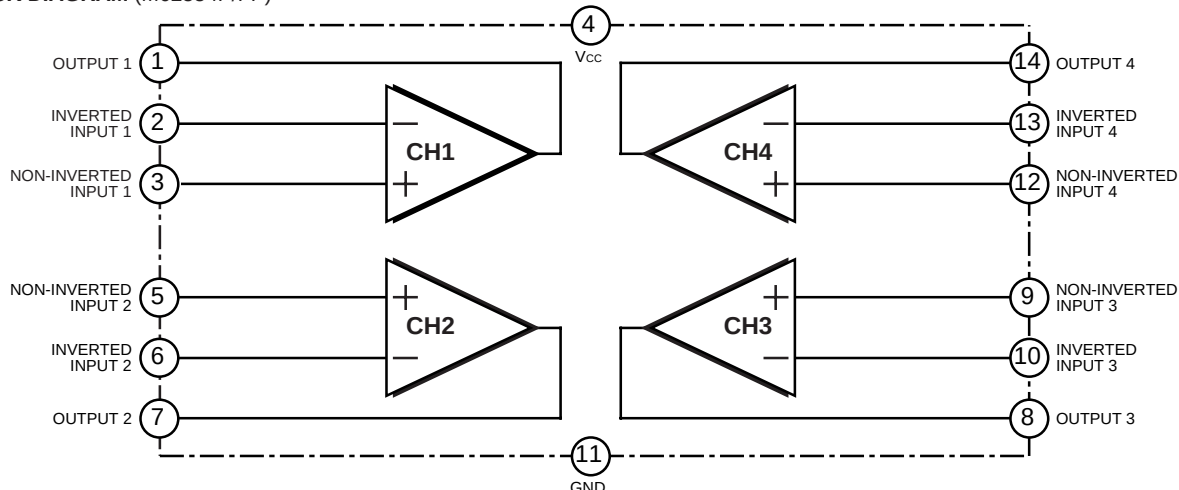


*Pin number at GP is put in parentheses.

BLOCK DIAGRAM (M62552P/FP/GP)



BLOCK DIAGRAM (M62554P/FP)



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ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise noted)

Symbol	Parameter	Conditions		Ratings	Unit
V _{CC}	Supply voltage			7	V
I _{sink} I _{source}	Load current			±10	mA
V _{IN}	Input voltage	V _{IN} ≤ V _{CC}		-0.3 to 7	V
V _{id}	Differential Input voltage			7	V
P _d	Power dissipation	Ta=25°C	M62551	450(L)/200(GP)	mW
			M62552	625(P)/440(FP)/280(GP)	
			M62554	700(P)/550(FP)	
K _{theta}	Thermal derating	Ta>25°C	M62551	4.5(L)2.0(GP)	mW/°C
			M62552	6.25(P)/4.4(FP)/2.8(GP)	
			M62554	7.0(P)/5.5(FP)	
T _{opr}	Ambient temperature			-20 to +85	°C
T _{stg}	Storage temperature			-40 to +125	°C

ELECTRICAL CHARACTERISTICS (Ta=25°C, V_{CC}=5V unless otherwise noted)

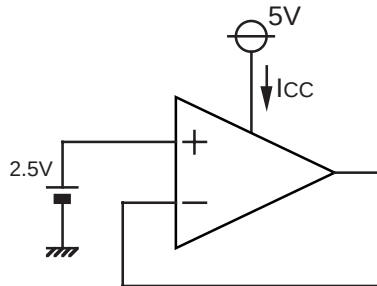
Symbol	Parameter	Test condition	Limits			Unit
			Min.	Typ	Max	
I _{CC}	Circuit current	G _v =0dB, R _L =∞	M62551	0.19	0.30	mA
			M62552	0.38	0.60	
			M62554	0.76	1.20	
V _{IO}	Input offset voltage	G _v =0dB, R _L =∞		4	8	mV
I _B	Input bias current			1	50	pA
V _{ICM}	Common mode voltage range		0		V _{CC}	V
G _{VO}	Open loop voltage gain	R _L ≥ 20KΩ	80	100		dB
V _{OH}	Output voltage swing	G _v =0dB, V _{IN} =V _{CC} , I _o =+5mA	V _{CC} -0.5	V _{CC} -0.1		V
		G _v =0dB, V _{IN} =V _{CC} , I _o =+1mA	V _{CC} -0.1	V _{CC} -0.02		
V _{OL}		G _v =0dB, V _{IN} =V _{CC} , I _o =-5mA		0.05	0.25	
		G _v =0dB, V _{IN} =V _{CC} , I _o =-1mA		0.01	0.1	
CMRR	Common mode rejection ratio			65		dB
SVRR	Supply voltage rejection ratio			65		dB
SR	Slew rate	G _v =0dB, R _L =∞		1.2		V/μS
f _T	Gain bandwidth product			1.0		MHz
V _{NI}	Input conversion noise voltage	V _{IN} =2.5V, R _s =1KΩ, BW:10Hz, 30KHz		5	10	μV _{rms}

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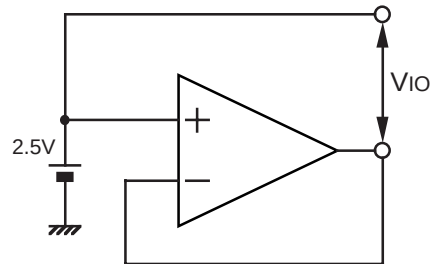
GENERAL PURPOSE C•MOS OP AMP(SINGLE/DUAL/QUAD)

MEASUREMENT CIRCUIT

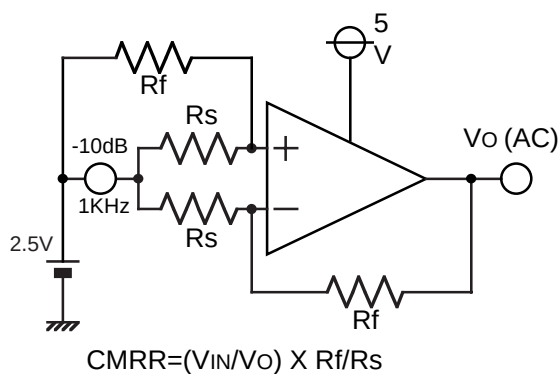
(1) CIRCUIT CURRENT



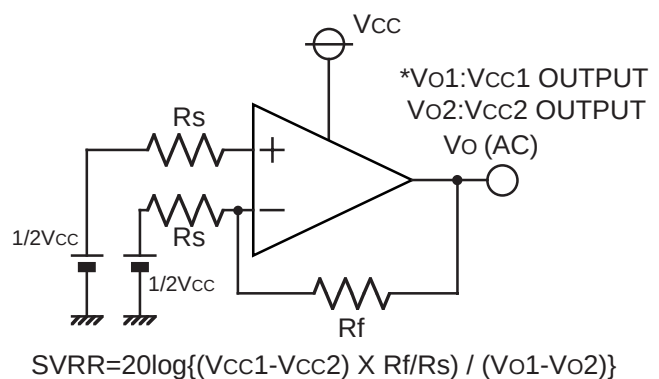
(2) INPUT OFFSET VOLTAGE



(3) COMMON MODE REJECTION RATIO

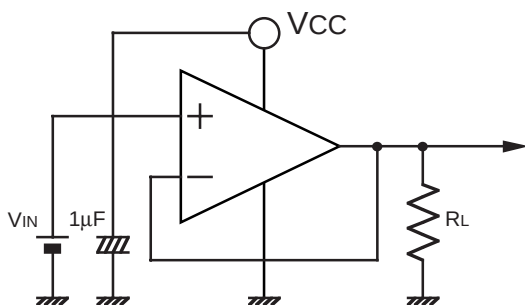


(4) SUPPLY VOLTAGE REJECTION RATIO

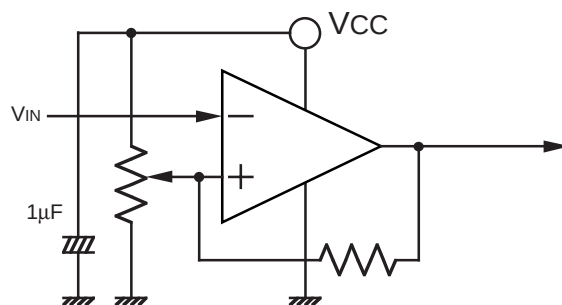


APPLICATION

(1) VOLTAGE FOLLOWER



(2) REVEL DETECTOR



⚠ Mitsubishi Electric Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit design, in order to prevent fires from spreading, redundancy, malfunction or other mishap.